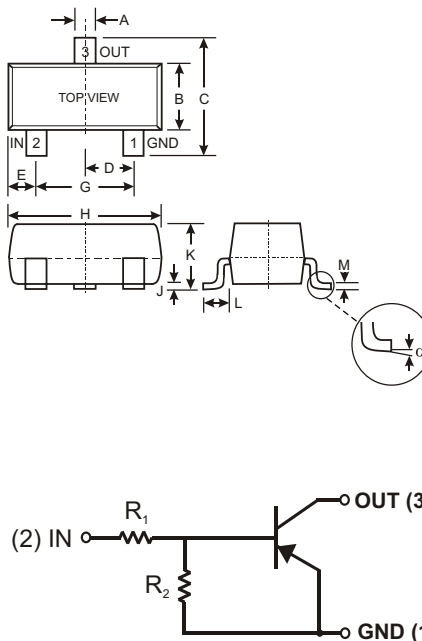


Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTD)
- Built-In Biasing Resistors, R1, R2
- Also Available in Lead Free Version

Mechanical Data

- Case: SOT-23, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Also Available in Lead Free Plating (Matte Tin Finish). Please see Ordering Information, Note 3, on Page 3
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 3)
- Weight: 0.008 grams (approx.)
- Ordering Information (See Page 3)



SOT-23		
Dim	Min	Max
A	0.37	0.51
B	1.20	1.40
C	2.30	2.50
D	0.89	1.03
E	0.45	0.60
G	1.78	2.05
H	2.80	3.00
J	0.013	0.10
K	0.903	1.10
L	0.45	0.61
M	0.085	0.180
α	0°	8°
All Dimensions in mm		

P/N	R1 (NOM)	R2 (NOM)	MARKING
DDTB113EC	1K	1K	P60
DDTB123EC	2.2K	2.2K	P61
DDTB143EC	4.7K	4.7K	P62
DDTB114EC	10K	10K	P63
DDTB122JC	0.22K	4.7K	P64
DDTB113ZC	1K	10K	P65
DDTB123YC	2.2K	10K	P66
DDTB133HC	3.3K	10K	P67
DDTB123TC	2.2K	OPEN	P69
DDTB143TC	4.7K	OPEN	P70
DDTB114TC	10K	OPEN	P71
DDTB114GC	0	10K	P72

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage, (3) to (1)	V _{CC}	-50	V
Input Voltage, (2) to (1)	V _{IN}	+10 to -10 +10 to -12 +10 to -30 +10 to -40 +5 to -5 +5 to -10 +5 to -12 +6 to -20	V
Input Voltage, (1) to (2)	V _{EBO} (MAX)	-5	V
Output Current	I _C	-500	mA
Power Dissipation	P _d	200	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C

Note: 1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

R1, R2 Types

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	$V_{I(off)}$	-0.5 -0.5 -0.5 -0.5 -0.5 -0.3 -0.3 -0.3	—	—	V	$V_{CC} = -5V, I_O = -100\mu A$
	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	$V_{I(on)}$	—	—	-3.0 -3.0 -3.0 -3.0 -3.0 -2.0 -2.0 -2.0	V	$V_O = -0.3V, I_O = -20mA$ $V_O = -0.3V, I_O = -20mA$ $V_O = -0.3V, I_O = -20mA$ $V_O = -0.3V, I_O = -10mA$ $V_O = -0.3V, I_O = -30mA$ $V_O = -0.3V, I_O = -20mA$ $V_O = -0.3V, I_O = -20mA$ $V_O = -0.3V, I_O = -20mA$
Output Voltage		$V_{O(on)}$	—	—	-0.3V	V	$I_O/I_I = -50mA/-2.5mA$
Input Current	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	I_I	—	—	-7.2 -3.8 -1.8 -0.88 -4.5 -7.2 -3.6 -2.4	mA	$V_I = -5V$
	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	$I_{O(off)}$	—	—	-0.5	μA	$V_{CC} = -50V, V_I = 0V$
DC Current Gain	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	G_I	33 39 47 56 47 56 56 56	—	—	—	$V_O = -5V, I_O = -50mA$
	DDTB113EC DDTB123EC DDTB143EC DDTB114EC DDTB122JC DDTB113ZC DDTB123YC DDTB133HC	f_T	—	200	—	MHz	$V_{CE} = -10V, I_E = -5mA, f = 100MHz$

* Transistor - For Reference Only

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

R1-Only, R2-Only Types

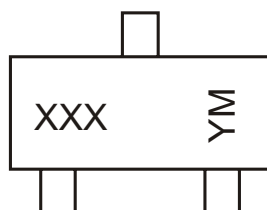
Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV_{CBO}	-50	—	—	V	$I_C = -50\mu A$
Collector-Emitter Breakdown Voltage		BV_{CEO}	-40	—	—	V	$I_C = -1mA$
Emitter-Base Breakdown Voltage	DDTB123TC DDTB143TC DDTB114TC DDTB114GC	BV_{EBO}	-5	—	—	V	$I_E = -50\mu A$ $I_E = -50\mu A$ $I_E = -50\mu A$ $I_E = -720\mu A$
	DDTB123TC DDTB143TC DDTB114TC DDTB114GC	I_{CBO}	—	—	-0.5	μA	$V_{CB} = -50V$
Emitter Cutoff Current	DDTB123TC DDTB143TC DDTB114TC DDTB114GC	I_{EBO}	— — — -300	—	-0.5 -0.5 -0.5 -580	μA	$V_{EB} = -4V$
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	—	—	-0.3	V	$I_C = -50mA, I_B = -2.5mA$
DC Current Transfer Ratio	DDTB123TC DDTB143TC DDTB114TC DDTB114GC	h_{FE}	100 100 100 56	250 250 250 —	600 600 600 —	—	$I_C = -5mA, V_{CE} = -5V$
Gain-Bandwidth Product*		f_T	—	200	—	MHz	$V_{CE} = -10V, I_E = 5mA, f = 100MHz$

* Transistor - For Reference Only

Ordering Information (Note 2)

Device	Packaging	Shipping
DDTB113EC-7	SOT-23	3000/Tape & Reel
DDTB123EC-7	SOT-23	3000/Tape & Reel
DDTB143EC-7	SOT-23	3000/Tape & Reel
DDTB114EC-7	SOT-23	3000/Tape & Reel
DDTB122JC-7	SOT-23	3000/Tape & Reel
DDTB113ZC-7	SOT-23	3000/Tape & Reel
DDTB123YC-7	SOT-23	3000/Tape & Reel
DDTB133HC-7	SOT-23	3000/Tape & Reel
DDTB123TC-7	SOT-23	3000/Tape & Reel
DDTB143TC-7	SOT-23	3000/Tape & Reel
DDTB114TC-7	SOT-23	3000/Tape & Reel
DDTB114GC-7	SOT-23	3000/Tape & Reel

Notes: 2. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.
 3. For Lead Free version (with Lead Free terminal finish) part number, please add "-F" suffix to part number above.
 Example: DDTB114GC-7-F.

Marking Information


XXX = Product Type Marking Code
 See Sheet 1 Diagrams
 YM = Date Code Marking
 Y = Year ex: N = 2002
 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D